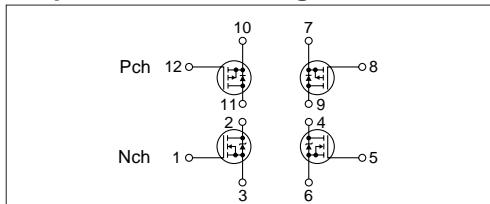
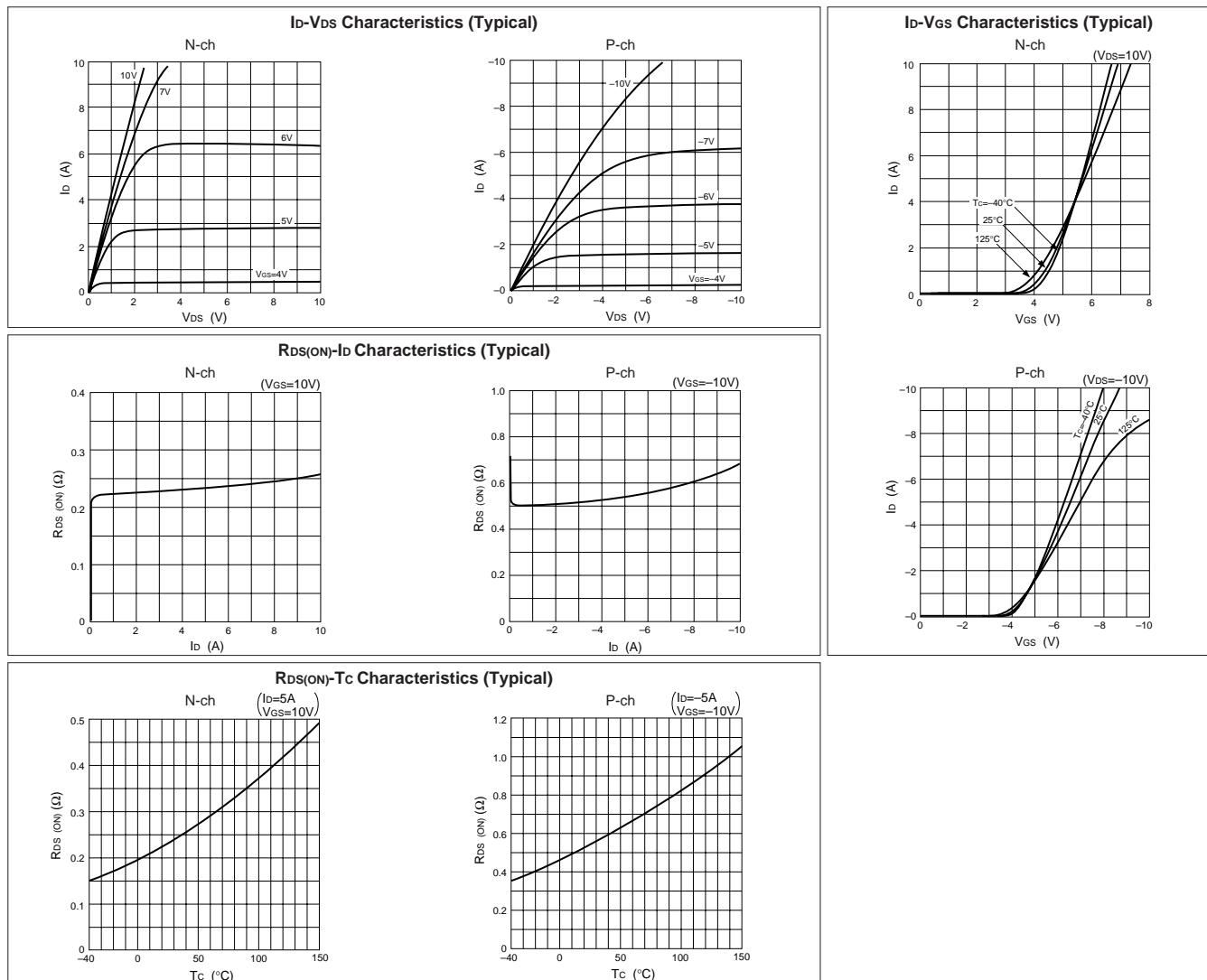


Absolute maximum ratings

(Ta=25°C)

Symbol	Ratings		Unit
	N channel	P channel	
V _{DSS}	100	-100	V
V _{GSS}	±20	±20	V
I _D	±5	±5	A
I _{D(pulse)}	±10 (PW≤1ms)	±10 (PW≤1ms)	A
E _{AS} *	30	—	mJ
P _T	5 (Ta=25°C, with all circuits operating, without heatsink)		W
	35 (Tc=25°C, with all circuits operating, with infinite heatsink)		W
θ _{j-a}	25 (Junction-Air, Ta=25°C, with all circuits operating)		°C/W
θ _{j-c}	3.57 (with all circuits operating, Tc=25°C, with all circuits operating)		°C/W
V _{ISO}	1000 (Between fin and lead pin, AC)		Vrms
T _{ch}	150		°C
T _{stg}	-40 to +150		°C

* : V_{DD}=20V, L=10mH, I_D=2.5A, unclamped, see Fig. E on page 15.

■ Equivalent circuit diagram

Characteristic curves


Electrical characteristics

(Ta=25°C)

Symbol	N channel						P channel					
	Specification			Unit	Conditions	Specification			Unit	Conditions		
	min	typ	max			min	typ	max				
V(BR)DSS	100			V	Id=250µA, Vgs=0V	-100			V	Id=-250µA, Vgs=0V		
Igss			±500	nA	Vgs=±20V				±500	nA	Vgs=±20V	
Idss			250	µA	Vds=100V, Vgs=0V				-250	µA	Vds=-100V, Vgs=0V	
VTH	2.0		4.0	V	Vds=10V, Id=250µA	-2.0			-4.0	V	Vds=-10V, Id=-250µA	
Re(yfs)	2.4	3.7		S	Vds=10V, Id=5A	0.9	2.0		S	Vds=-10V, Id=-5A		
RDS(ON)		0.27	0.30	Ω	Vgs=10V, Id=5A		0.55	0.7	Ω	Vgs=-10V, Id=-5A		
Ciss		350		pF	Vds=25V, f=1.0MHz, Vgs=0V		300		pF	Vds=-25V, f=1.0MHz, Vgs=0V		
Coss		130		pF			200		pF			
t _{on}		60		ns	Id=5A, Vdd=50V, Vgs=10V, see Fig. 3 on page 16.		150		ns	Id=-5A, Vdd=-50V, Vgs=-10V, see Fig. 4 on page 16.		
t _{off}		40		ns			200		ns			
V _{SD}		1.1	1.8	V	Isd=5A, Vgs=0V		-4.5	-5.5	V	Isd=-5A, Vgs=0V		
t _{rr}		330		ns	Isd=±100mA		220		ns	Isd=±100mA		

Characteristic curves

